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# Impact of alkyl side chain on the photostability and optoelectronic properties of indacenodithieno[3,2-b]thiophene-alt -naphtho[1,2-c:5,6-c]bis[1,2,5]thiadiazole medium bandgap copolymers

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# Abstract

Three donor- $\Box$ -acceptor (D- $\Box$ -A) type alternating conjugated polymers, namely PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD bearing the same backbone of indacenodithieno[3,2-*b*]thiophene (IDTT) as the D unit and naphtho[1,2-*c*:5,6-*c*']bis[1,2,5]thiadiazole (NT) as the A moiety but with different flexible side chain (*n*-hexadecyl (C16), 2-hexyldecyl (HD) and 2-octyldodecyl (OD)) substituted thiophene employed as  $\Box$ -bridges, were synthesized and characterized. The effects of the side chain on absorption, photostability, energy levels, aggregation, backbone conformation, morphology and photovoltaic properties were systematically investigated. Because moderate D and strong A units were selected to construct the polymer backbone, a medium optical bandgap (*ca.* 1.66 eV) and low-lying highest occupied molecular orbital energy level ( $E_{HOMO} \approx -5.36$  V), thus resulting in a relatively higher open-circuit voltage ( $V_{OC}$ ) of 0.80-0.83 V, were achieved. It was found that the side chain gave rise to an insignificant impact on absorption, aggregation and photostability in chlorobenzene solution and energy levels but a non-negligible influence on absorption, photostability and aggregation behavior in the film state. It was found that PIDTT-DTNT-C16 with the densest and most ordered packing structure exhibited the best photostability. Inverted bulk heterojunction polymer solar cells based on PIDTT-DTNT-HD:PC<sub>61</sub>BM ([6,6]-phenyl-C<sub>61</sub>-butyric acid methyl ester) showed at least a 1.5-fold increase in power conversion efficiency, chiefly originating from its slightly improved absorption, more balanced  $\Box_h/\Box_e$  ratio and favorable morphology of the active layer as a result of incorporating branched HD side chains into the IDTT-*alt*-DTNT backbone.

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Supporting information may be found in the online version of this article.

Keywords: naphtho[1,2-c:5,6-c']bis[1,2,5]thiadiazole; indacenodithieno[3,2-b]thiophene; alkyl side chain; aggregation; photostability

# INTRODUCTION

Currently, polymer solar cells (PSCs) adopting bulk heterojunction (BHJ) architecture have attracted substantial academic and industrial enthusiasm owing to their potential advantages of low cost, light weight, flexibility in fabrication and a low temperature solution processing technique.<sup>1-4</sup> Such BHJ PSCs, utilizing a solution-processed active layer made up of an electron donor (D) (i.e. D-conjugated polymers) and an electron acceptor (A) (i.e. [6,6]-phenyl-C<sub>61</sub>-butyric acid methyl ester (PC<sub>61</sub>BM) or 3,9-bis(2-methylene-(3-(1,1-dicyanomethylene)indanone))-5,5,11, 11-tetra(4-hexylphenyl)dithieno[2,3-d:2',3'-d']-s-indaceno[1,2-b: 5.6-b']dithiophene (ITIC) etc.), sandwiched between indium tin oxide (ITO) and metallic electrodes, not only can provide abundant D-A interfaces for exciton dissociation into free charges but also can form an interpenetrating network for free charge transport to the corresponding collecting electrodes.5 Benefitting from tremendous efforts related to novel materials or new device

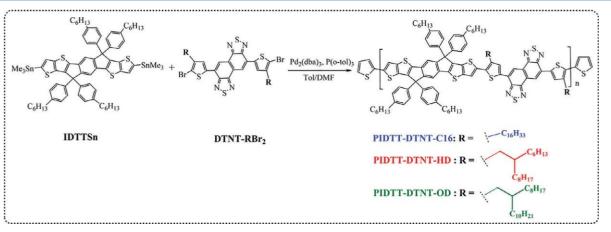
architectures, the power conversion efficiencies (PCEs) for single junction PSCs, prepared under laboratory conditions, have already exceeded over 15%.<sup>6,7</sup> However, there are still challenges for PSCs

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to meet the demand of commercialization. To further elevate the efficiency, exploring new conjugated polymers (CPs) plays a significant role. Commonly, in terms of harvesting solar energy (i.e. optical bandgaps  $E_g^{opt}$ ), CP materials can be classified into three categories: low bandgap (LBG) ( $E_g^{opt} < 1.6 \,\text{eV}$ ), medium bandgap (MBG)  $(E_a^{opt} 1.6 - 1.8 \text{ eV})$  and wide bandgap (WBG)  $(E_a^{opt} > 1.8 \text{ eV})$ .<sup>5,8</sup> Recently, most successful donor CPs for solar cell application have been designed to be LBG materials because, the lower the bandgap, the more sunlight can be absorbed, which can broaden the absorption to extend to the near-infrared region and acquire higher short-circuit current density  $(J_{SC})$ . However, it was unreasonable to over-approach the highest occupied molecular orbital (HOMO) energy level ( $E_{HOMO}$ ) and the lowest unoccupied molecular orbital (LUMO) energy level ( $E_{LUMO}$ ). Elevating the HOMO level may reduce the open-circuit voltage ( $V_{OC}$ ); meanwhile the  $E_{\rm LUMO}$  level was higher (usually larger than about 0.3 eV) than the electron acceptor so as to supply enough driving force for charge separation.<sup>2</sup> Additionally, the intrinsic narrow absorption bands for LBG CPs would limit broad photon harvesting and prevent making full use of the entire solar spectrum.<sup>3</sup> Compared to the well-developed LBG counterparts, the development of MBG and WBG copolymers are less important. Nevertheless, they are still of importance for PSCs because the MBG and WBG copolymers can match with the non-fullerene electron acceptors so as to simultaneously obtain complementary absorption and a deeper  $E_{HOMO}$ , and thus obtain both enhanced  $J_{SC}$  and  $V_{OC}$  of PSCs.<sup>9</sup> Meanwhile, they are also used as vital components in tandem devices and can facilitate tandem cells to harvest more solar light.<sup>10</sup> Therefore, it is highly desirable to design WBG and MBG CPs and further understand the structure-property relationships governing the material performance.

Solution-processed CPs mainly contain D-conjugated backbones and flexible solubilizing side chains hung perpendicularly.<sup>11–14</sup> The most successful strategy to construct the □-conjugated backbones of CPs is by incorporating an electron-rich (D) moiety and an electron-deficient (A) unit and alternating them in their repeating units via molecular orbital hybridization, which can take advantage of photo-induced intramolecular charge transfer (ICT) from D to A, and the bandgap, hole mobility and electron energy levels can be easily tuned by finely selecting the D and A units.<sup>15–28</sup> Beyond tuning the conjugated backbones of CPs, selecting suitable side chains is also a viable and effective method for elevating the efficiency. The roles of the side chains are not confined to molecular weight, solubility and solution-processed properties. In fact, the number, branch, length and rigidity of the side chains as well as the position of the CP frameworks have an increasing impact in regulating the optical absorption, thermal stability, photostability, crystallinity, molecular orientation and morphology in the active layers.<sup>12,14,29–37</sup> Recently, many efforts have been devoted to comprehending the effect of the side chain on the functional and optoelectronic properties of CPs. Studies of well-known poly(3-alkylthiophene)s have shown that not only the length of the alkyl side chain affects the solubility but also a longer one decreases the absorbance, stacking and hole mobility.<sup>31</sup> Wang et al. prepared three CPs bearing a carbazole-thiophene-quinoxaline-thiophene backbone and tuned the shape and length of the side chain; they found that poly{9-octylcarbazole-2,7-diyl-alt-5,8-bis(thien-2-yl)-2,3-bis(3-(octyloxy)phenyl)quinoxaline-5,5'-diyl} (EWC3) bearing the largest side chain yielded the highest PCE and Voc.32 Beaujuge and colleagues changed the size and branching position of the side chains in the poly{benzo[1,2-b:4,5-b']dithiophene-altthieno[3,4-c]pyrrole-4,6-dione} (PBDT-TPD) family and found that the polymer backbone orientation exhibited a critical change, i.e. the preferential 'face-on' disappeared and thus the PCE was lowered when the branched chain was replaced by a linear one.<sup>33</sup> Li *et al.* found that the width of the fibrillar microstructure of blend films was decreased which could facilitate exciton dissociation, and thus the shortest-chain-containing poly{*N*,*N*-di(2-hexyldecyl)diketopyrrolopyrrole-*alt*-thiophene-phe nylene-thiophene} (HD-PDPPTPT) yielded the best PCE of 7.4%, with decrease of the side chain length in the crystalline poly{diketopyrrolopyrrole-*alt*-thiophene-phenylene-thiophene} (PDPP-TBT) family CPs.<sup>34</sup> Huang and colleagues studied two naphtho[1,2-c:5,6-c']bis[1,2,5]thiadiazole-based CPs and shortened the spacer's side chain from 2-decyltetradecyl (DT) (NT1014) to 2-octyldodecyl (OD) (NT812), which induced the formation of the favorable 'face-on' orientation, and thus the PCE was remarkably enhanced from 3.03% to 10.33%.<sup>35</sup> Recently, our group found that a tiny change of alkyl side chain (from 2-hexyldecyl (HD) to OD) in the poly[4,8-bis[5-(2-butyloctyl) thieno[3,2-b]thien-2-yl]benzo[1,2-b:4,5-b']dithiophene-2,6-diyl-alt-4,9-bis(thien-2-yl)naphtho[1,2-c:5,6-c']bis[1,2,5]thiadiazole-5, 5'divl](PBDT-TT-DTNT) family enhanced the PCE, owing to 2-fold higher mobility, favorable phase separation and enhanced exciton dissociation.<sup>14</sup> It was not difficult to see that the correlation between side chain structure and photovoltaic (PV) properties was complicated and it was premature to draw effect laws; therefore it was of crucial importance to precisely make a balance between the side chain of CPs, solution processability, backbone, stacking, charge transport, morphology and PV performance.

Recently, highly fused electron arenes have been widely focused on and exhibited appealing optoelectronic applications.<sup>38–41</sup> By fastening or fusing adjacent rings, the rigid backbones can be extended horizontally or vertically. It has been demonstrated that highly fused aromatic/heteroaromatic units not only can enhance the effective conjugation and overlap of D-orbitals along the polymer backbone to facilitate electron delocalization, which is propitious for acquiring a red-shifted absorption spectrum, but can also be conducive to intermolecular charge carrier hopping and restraining the interannular rotation in order to reduce the Marcus reorganization energy, resulting in an improved intrinsic charge mobility.<sup>42–49</sup> Among the numerous D units, one appealing D moiety is a penta-ring indacenodithiophene (IDT) and plenty of IDT-based CPs with excellent PV performance have been reported.<sup>42,43,50,51</sup> Xu etal. found that the PCE was increased from 5.97% to 7.03% as a result of an improved mobility of the longer effective conjugation and better planarity evoked by a hepta-ring indace nodithieno [3,2-b] thiophene (IDTT) unit by extending D-conjugation along the IDT linear backbone.<sup>43</sup> Cai et al. also demonstrated that a 1,3-bis (thien-2-yl)-5,7-bis(2-ethylhexyl)benzo[1,2-c:4,5-c']dithiophene-4, 8dione (T1)-based CP IDTT-T1 exhibited 5.5-fold higher fieldeffect transistor mobility than that of IDT-T1 and thus the PCE was raised from 6.26% to 6.58%.44 Furthermore, the hepta-ring of IDTT was expanded to an undeca-ring IDTbiscvclo-pentadithiophene (IDTCPDT) by Li et al. and it was found that fully rigidified difluorobenzothiadiazole (DFBT)-based CP PIDTCPDT-DFBT exhibited a wider and stronger absorption band, a reduced reorganizational energy from 4.1 to 3.2 kcal mol<sup>-1</sup> and a 1-order-elevated hole mobility; thus the  $J_{\rm SC}$  was increased from 10.40 to 14.59 mA cm<sup>-2</sup>,<sup>49</sup> which made these IDTT-based CPs gain particular interest.<sup>43–49,52–56</sup> Among the many electron acceptor units, a tetracyclic heteroaromatic ring



Scheme 1. Syntheses of copolymers PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD.

naphtho[1,2-c:5,6-c']bis[1,2,5]thiadiazole (NT) fused by double benzothiadiazole (BT) rings, exhibiting an enlarged planarity and stronger electron-accepting ability has been widely applied in the PV field.<sup>24,35,57–64</sup> For example, excellent NT was first introduced into the polymer backbone instead of BT by Huang's group; it was found that PBDT-DTNT exhibited a remarkably extended absorption profile, decuple higher charge mobility and therefore 2.84 times higher PCE than its counterpart PBDT-DTBT even though a decreased V<sub>OC</sub> resulted from an elevated E<sub>HOMO</sub>.<sup>58</sup> Furthermore, another NT-based star material was composed of DTNT and 2,2'-bithiophene moieties, or composed of NT and tetrathiophene (PNTz4T) combining NT with the electron-richer oligothiophene tetrathiophene was developed by Osaka's group and showed a narrower bandgap, a lower-lying  $E_{HOMO}$ , a more highly ordered structure and thus a 2.48 times enhanced PCE compared to PBTz4T.<sup>59</sup> Recently, we utilized NT to replace BT in triisopropy-Isilylethynyl substituted dithienobenzodithiophene-based CPs, and the PCE was enhanced by 1.29 times originating from greatly widened absorption, deepened  $E_{HOMO}$ , better coplanarity and elevated mobility, as well as the favorable morphology in the active layer.64 Based on the above facts, it is of importance to synthesize CPs containing the hepta-ring fused IDTT moiety and an NT unit bearing a highly D-extended structure and stronger electron affinity and to further attempt to make a thorough inquiry into the structure- property correlation.

In consideration of the desirable properties of IDTT and NT moieties, herein, a family of D-D-A type MBG CPs containing different flexible side chains n-hexadecyl (C16), HD and OD of □-bridge thiophene, namely PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD, respectively, in which fused hepta-ring IDTT and centrosymmetric NT moieties are used as D and A units (Scheme 1), were synthesized to systematically investigate the impact of the side chain on the photophysical properties, photostability, electrochemical properties, backbone conformation and PV properties. A medium ICT interaction was formed, leading to an MBG of approximately 1.66 eV which is close to that of PIDT-DTNT (1.65 eV)<sup>50</sup> but smaller than that of PIDTT-DTFBT-T,<sup>56</sup> owing to the combination of the strong A unit of NT with the medium D of IDTT. It was found that the side chain gave rise to an insignificant impact on absorption and photostability in chlorobenzene (CB) solution and energy levels but a non-negligible influence on absorption, photostability and aggregation in the film state. It was found the PIDTT-DTNT-C16 with linear side chain exhibited the best photostability, while the PIDTT-DTNT-HD:PC<sub>61</sub>BM based device showed

the best PCE, which was obviously higher than those containing the other two side chains (C16 and OD).

# EXPERIMENTAL

## Measurement and characterization

<sup>1</sup>H NMR spectra, melting point tests, C, H and N elemental analyses, TGA analyses, molecular weight of the polymers, UV – visible absorption, electrochemical properties, and AFM and TEM images were obtained according to our reported methods.<sup>24</sup> The photostability of the polymers and XRD were measured according to our reported methods.<sup>25</sup>

# Materials

All utilized chemical reagents were reagent grade and were purchased from J&K Scientific, TCI Chemical Co. and Sigma-Aldrich Co. and were used without further purification. Solvents such as tetrahydrofuran, n-hexane and diethyl ether (Et<sub>2</sub>O) were dried over sodium/benzophenone and freshly distilled prior to use. 4,9-Bis(5-bromo-4-(2-hexyldecyl)thien-2-yl)naphtho[1,2-c:5,6-c] bis[1,2,5]thiadiazole (DTNT-HDBr<sub>2</sub>), 4,9-bis(5-bromo-4-(2-octyldodecyl)thien-2-yl)naphtho[1,2-c:5,6-c']bis[1,2,5]thiadiazole (DTNT-ODBr<sub>2</sub>)<sup>14,24</sup> and polyelectrolyte poly[(9,9-bis-(3'-(N,N-dime thylamino)propyl)-2,7-fluorene)-alt-2,7-(9,9-dioctylfluorene)] (PFN)65 were synthesized according to the corresponding references. 2,8-Bis(trimethyltin)-6,6,12,12-tetra(4-hexylphenyl)indacen odithieno[3,2-b]thiophene (IDTTSn)<sup>43,66</sup> and 4,9-bis(5-bromo-4-(nhexadecyl)thien-2-yl)naphtho[1,2-c:5,6-c']bis[1,2,5]thiadiazole (DTNT-C16Br<sub>2</sub>) were synthesized as described in Appendix S1.

## Synthesis procedures

The general procedure adopted for polymer synthesis was as follows. Carefully purified bistin monomer IDTTSn and dibromo-monomer (DTNT-C16Br<sub>2</sub>, DTNT-HDBr<sub>2</sub> and DTNT-ODBr<sub>2</sub>) were dissolved into 6 mL degassed dry toluene and 0.8 mL *N*,*N*-dimethylformamide (DMF) in a 25 mL two-neck round-bottom flask under Ar. The mixture was bubbled with Ar for an additional 20 min to remove O<sub>2</sub>. Thereafter, Pd<sub>2</sub>(dba)<sub>3</sub>(1.4 mg) and P(o-tolyl)<sub>3</sub> (2.3 mg) were quickly added to the mixture in one portion and the solution was bubbled with Ar for another 20 min. The mixture was then vigorously refluxed for 48 h under Ar, followed by the subsequent addition of 2-tri(butylstannyl)thiophene and 2-bromothiophene at an interval of 8 h for end-capping. After refluxing for an additional 8 h, the mixture was poured into 300 mL methanol. The precipitate was collected by filtration and the crude polymer was subjected to Soxhlet extraction successively with ethanol, acetone, hexane and toluene. The toluene fraction was condensed to about 6 mL and precipitated into methanol. The black solid was collected and completely dried under vacuum overnight to obtain the target material with yields of 83.3%-92.3%.

Synthesis of poly[6,6,12,12-tetra(4-hexylphenyl)indacenodithieno [3,2-b]thiophene-2,8-diyl- alt-4,9-bis(4-(n-hexadecyl)thien-2-yl) naphtho[1,2-c:5,6-c']bis[1,2,5]thiadiazole-5,5'-diyl]

#### (PIDTT-DTNT-C16)

IDTTSn (134.5mg, 0.10mmol) and DTNT-C16Br<sub>2</sub> (101.5mg, 0.10 mmol) were used to prepare PIDTT-DTNT-C16 according to the general procedure illustrated above. A black solid with metallic luster of about 172.8 mg (PIDTT-DTNT-C16) was obtained with a yield of 92.3%.

Number-average molecular weight ( $M_n$ ) = 29.4 kDa, polydispersity index (PDI) 2.5. <sup>1</sup>H NMR (400 MHz, CDCI<sub>3</sub>), □ (ppm): 9.08 (br, ArH), 8.17 (br, ArH), 7.55 (br, ArH), 7.47 (m, ArH), 7.24 (m, ArH), 7.15 (br, ArH), 7.13 (br, ArH), 2.84 (br, CH\_2), 2.59 (m, CH\_2), 1.85 (br, CH\_2), 1.61 (br, CH\_2), 1.35–1.20 (m, CH\_2), 0.85–0.82 (m, CH\_2). Analysis call

culated for C<sub>118</sub>H<sub>142</sub>N<sub>4</sub>S<sub>8</sub>: C, 75.67%; H, 7.64%; N, 2.99%. Found: C, 75.51%; H, 7.50%; N, 3.10%.

Synthesis of poly[6,6,12,12-tetra(4-hexylphenyl)indacenodithieno [3,2-b]thiophene-2,8-diyl- alt-4,9-bis(4-(2-hexyldecyl)thien-2-yl) naphtho[1,2-c:5,6-c']bis[1,2,5]thiadiazole-5,5'-diyl]

#### (PIDTT-DTNT-HD)

IDTTSn (172.8mg, 0.128mmol) and DTNT-HDBr<sub>2</sub> (130.4mg, 0.128 mmol) were used and the polymer PIDTT-DTNT-HD was collected as a black solid with metallic luster (209.7 mg). Yield 87.2%. M<sub>n</sub> = 32.4 kDa, PDI = 2.2.

<sup>1</sup>HNMR (400 MHz, CDCl<sub>3</sub>), [] (ppm): 9.07 (br, ArH), 8.17 (br, ArH), 7.55 (br, ArH), 7.48 (m, ArH), 7.24 (m, ArH), 7.15 (br, ArH), 7.13 (br, ArH), 2.85 (br, CH<sub>2</sub>), 2.59 (m, CH<sub>2</sub>), 1.85 (br, CH), 1.61 (br, CH<sub>2</sub>), 1.35–1.20 (m, CH<sub>2</sub>), 0.87–0.80 (m, CH<sub>3</sub>). Analysis calculated for C<sub>118</sub>H<sub>142</sub>N<sub>4</sub>S<sub>8</sub>: C, 75.67%; H, 7.64%; N, 2.99%. Found: C, 75.61%; H, 7.42%; N, 3.05%.

Synthesis of poly[6,6,12,12-tetra(4-hexylphenyl)indacenodithieno [3,2-b]thiophene-2,8-diyl- alt-4,9-bis(4-(2-octyldodecyl)thien-2-yl) naphtho[1,2-c:5,6-c']bis[1,2,5]thiadiazole-5,5'-diyl]

#### (PIDTT-DTNT-OD)

IDTTSn (144.5mg, 0.107mmol) and DTNT-ODBr<sub>2</sub> (121.4mg, 0.107 mmol) were used. The polymer PIDTT-DTNT-OD was collected as a black solid with metallic luster (177.0 mg, yield 83.3%). M<sub>n</sub>=34.3kDa, PDI=2.1. <sup>1</sup>HNMR (400MHz, CDCI<sub>3</sub>), □ (ppm): 9.03 (br, ArH), 8.17 (br, ArH),

7.56 (br, ArH), 7.47 (m, ArH), 7.25 (m, ArH), 7.16 (br, ArH), 7.14 (br, ArH), 2.88 (br, CH<sub>2</sub>), 2.60 (m, CH<sub>2</sub>), 1.79 (br, CH), 1.61 (br, CH<sub>2</sub>), 1.35-1.20 (m, CH<sub>2</sub>), 0.87 (br, CH<sub>3</sub>). Analysis calculated for C<sub>126</sub>H<sub>158</sub>N<sub>4</sub>S<sub>8</sub>: C, 76.23%; H, 8.02%; N, 2.82%. Found: C, 76.01%; H, 7.81%; N, 2.70%.

#### Fabrication and characterization of the photovoltaic cells

The detailed procedure for fabrication and characterization of the PSCsisgiven in Appendix S1.

#### Hole-only and electron-only device fabrication and measurement

The detailed procedure for hole-only and electron-only devices<sup>64,67</sup> is also given in Appendix S1.

## RESULTS AND DISCUSSION

#### Synthesis and characterization

The general synthetic route for bistin comonomer IDTTSn, including the three steps Negishi coupling, double nucleophilic additionintramolecular Friedel-Crafts annulation, and distannylation, is depicted in Appendix S1, Scheme S1, according to references<sup>43,66</sup>. The yields of these synthetic procedures were 80%, 65% and 80%, respectively. Furthermore, dibromide DTNT-C16Br<sub>2</sub> was synthesized according to our reported method.<sup>14,24</sup> These key intermediates and comonomers have been characterized and identified by NMR (Appendix S1, Figs S1-S5) and elemental analyses. Note that an increase of 20 °C in the melting point for DTNT-C16 after dibromination was found; more importantly, <sup>1</sup>H NMR of DTND-C16Br<sub>2</sub> was detected in o-dichlorobenzene-d4 (o-DCB-d4) because of poor solubility at elevated temperature (Appendix S1, Fig. S5), demonstrating that DTNT-C16Br<sub>2</sub> had been successfully brominated. As elucidated in Scheme 1, the resultant copolymers PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD were prepared by means of typical Stille polymerization utilizing Pd<sub>2</sub>(dba)<sub>3</sub> and tri(o-tolyl)phosphine as the catalyst system in toluene/DMF solution.<sup>68</sup> At the end of polymerization, end-capping was performed with 2-tri(butylstannyl)thiophene and 2-bromothiophene for enhancing the copolymer stability.<sup>69</sup> Purification of the resulting copolymers was carried out by our reported method.<sup>24</sup> Finally, the toluene-soluble fraction was recovered by re-precipitation in MeOH and then dried under vacuum overnight to remove the residual solvents. All polymers were obtained as black metallic luster solids with higher yields of 83.3%-92.3%. Furthermore, these resultant copolymers had good solubility in chlorinated solvents such as chloroform, CB and o-dichlorobenzene, which satisfied the requirements for solution-processed fabrication for PSCs.

The structures of the obtained copolymers were identified by <sup>1</sup>H NMR spectra, as shown in Appendix S1, Figs S6-S8. Three copolymers showed the distinct <sup>1</sup>H NMR signal in the aromatic regions. The peaks in the range of 9.08–9.02 ppm can be attributed to aromatic hydrogen of the NT core and those at 8.16-8.17 ppm can be ascribed to aromatic hydrogen of different flexible side chain substituted thiophene spacers. Meanwhile, peaks situated at 7.56–7.46 ppm can be assigned to aromatic hydrogen of the IDTT core and those at 7.24-7.12 ppm were assigned to aromatic hydrogen of hexylphenyl attached to IDTT. The peaks located at 2.84 – 2.88 ppm belonged to the signal of CH<sub>2</sub> directly linked to the thiophene spacer and those at 2.60–2.57 ppm originated from the signal of CH<sub>2</sub> directly linked to the hexylphenyl group. The peaks at 1.61-0,80ppm were ascribed to the signals of remaining CH<sub>2</sub> and CH<sub>3</sub> of the flexible side chains. Moreover, the results of elemental analysis were also in accordance with the theoretical values. *M*<sub>n</sub> values of the resultant PIDTT-DTNT-based copolymers were tested by gel permeation chromatography (Table S1 in Appendix S1). The values of  $M_n$  and the PDIs were found to be approximately 32.4 kDa and 1.8 for PIDTT-DTNT-C16, 31.2 kDa and 1.9 for PIDTT-DTNT-HD, and 34.4 kDa and 2.1 for PIDTT-DTNT-OD, respectively. These copolymers had similar molecular weights, so the particular effect of molecular weight on property could be overlooked. We measured the thermal properties of these copolymers through TGA. From Fig. S9 and Table S1 in Appendix S1, three copolymers exhibited a decomposition temperature ( $T_d$ , 5% weight-loss temperature) over 340 °C, which can guarantee the fabrication of devices in PSCs.

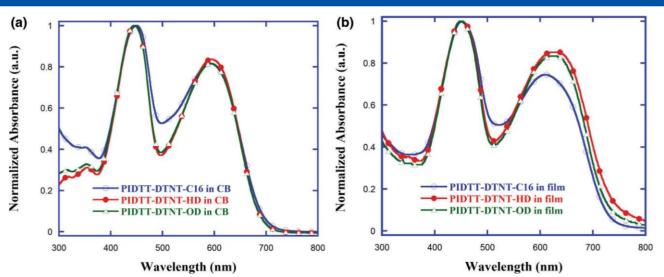


Figure 1. Normalized UV-visible absorption spectra of copolymers PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD in dilute CB solution (a) and asathinfilmspin-castfromCB(b).

	Solution	Film					
Polymer	D <sub>max</sub> (nm)	D <sub>max</sub> (nm)	D <sub>onset</sub> (nm)	E <sup>opta</sup> (eV)	□ <sup>onset</sup> (V)	E <sub>HOMO</sub> <sup>b</sup> (eV)	E <sub>LUMO</sub> <sup>c</sup> (eV)
PIDTT-DTNT-C16	448, 593	454, 610	742	1.67	0.68	-5.36	-3.69
PIDTT-DTNT-HD	446, 595	450, 628	750	1.65	0.68	-5.36	-3.71
PIDTT-DTNT-OD	446, 595	450, 625	746	1.66	0.70	-5.38	-3.72

<sup>c</sup>  $E_{LUMO}$  calculated from  $E_{g}^{opt}$  and  $E_{HOMO}$  for the copolymers:  $E_{LUMO} = E_{HOMO} + E^{opt}$  (eV).

## **Optical properties**

In order to determine the effects of the side chains on the

optoelectronic properties of the synthesized IDTT-alt-DTNT-based copolymers, the normalized UV- visible absorption spectra of each copolymer in a CB solution and as thin films are shown in Fig. 1; the summarized data are also listed in Table 1. It was observed that there were two obvious absorption bands for the three studied copolymers both in CB solution and as solid films. These short-wavelength absorbance bands ranging from 380 to 500 nm could be ascribed to a delocalized □-□\* transition of the polymer backbone, while relatively weaker bands ranging from 500 nm to 750 nm in the long-wavelength region could be attributed to the ICT from electron-rich IDTT units to electron-deficient NT moieties.<sup>50,52</sup> In the CB solution, three CPs exhibited similar absorption profiles with maximum absorption peakat446-448nm and a secondary peak at ca593 nm. Ongoing from solution to film, a red-shifted tendency for both D-D\* and ICT transition peaks of the resultant CPs were observed. Interestingly, a pronounced red-shift by 35 nm from 593 to 628 nm for PIDTT-DTNT-HD, a medium red-shift by 30 nm from 595 to 625 nm for PIDTT-DTNT-OD and the weakest red-shift by 17 nm from 593 nm to 610 nm for PIDTT-DTNT-C16 were observed, indicating that PIDTT-DTNT-C16 exhibited the strongest solid aggregation trend, which was identical with the later XRD and density functional theory (DFT) calculation. Furthermore, the optical bandgaps  $(E_a^{opt})$  for PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD

were calculated to be 1.67, 1.65 and 1.66 eV, respectively, using the equation  $E_g^{opt} = 1240/\Box_{onset}^{film}$  It should be noted that the bandgap was close to the IDT-based CP PIDT-DTNT<sup>50</sup> but obviously smaller than the BT-based PIDTT-DFBT-T of 1.75 eV,<sup>56</sup> suggesting that an electron-withdrawing unit (DTFBT versus DTNT) has more impact on the absorption property than an electron-rich unit (IDT versus IDTT) in this copolymer family. In addition to the absorption profile, the absorption coefficient was another important factor used for judging the ability of harvesting solar light energy for the CPs.<sup>14,24,64</sup> Therefore, the molar absorption coefficients ( $\square_{soln}$  and I<sub>film</sub>) of these studied CPs both in CB solution and as solid film were measured, as shown in Figs S10 and S11 in Appendix S1. It was shown that when the side chain was changed from C16 to HD to OD, the absorption coefficient in CB solution exhibited a decreased trend (from 83 731 to 81 183 to 71 387 L mol<sup>-1</sup> cm<sup>-1</sup>), while the absorption coefficient in the film state was first slightly enhanced and then decreased (from 16323 to 16611 to 14721 cm<sup>-1</sup>), implying that the type and length of the flexible side chain had little impact on the absorption profile and coefficient. The relatively larger decrease of D<sub>film</sub> in the PIDTT-DTNT-OD film may be affected by its relatively weak molecular aggregation obtained from the XRD analysis (later). Overall, PIDTT-DTNT-HD exhibited a slightly wider absorption and enhanced absorption compared with the other two polymers in the solid film state.

It has been proved that the molecule motions of CPs are bound to be accelerated with an elevating temperature, which leads

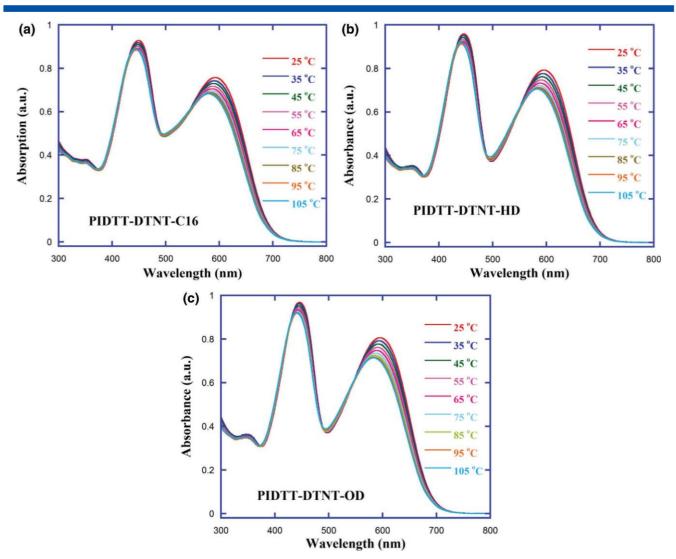


Figure 2. Temperature-dependent absorption spectra for the resultant copolymers PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD in CB with a concentration of about  $10^{-5}$  mol L<sup>-1</sup>.

to a reduction of the absorption shoulder peaks connected to the aggregation caused by the intermolecular  $\Box - \Box^*$  transition. That is, the distortion of the conjugated backbone is intensified at an elevated temperature, resulting in a reduction of the effective conjugation length for the polymer backbone, and thus the absorption peaks produced by the delocalized D-D\* transitions and those emerging by ICT transitions are both blue-shifted.14,24,64 To gain insight into the aggregation variations of different side chains, temperature-dependent absorption spectra of the synthesized copolymers PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD in CB solution were measured from 25 to 115 °C with a 10 °C interval, as depicted in Fig. 2. It was shown that, when the temperature was elevated, the three copolymers showed a similar trend, i.e. the ICT and D-D\* absorption peaks were both blue-shifted and both the absorption intensities decreased. In detail, the blue-shifted value and the decreased absorption intensity were 12.5 nm (from 592.5 to 580.0 nm) and 9.9% for PIDTT-DTNT-C16, 13.0 nm (from 595.5 to 582.5 nm) and 10.8% for PIDTT-DTNT-HD and 12 nm (from 595.5 to 583.5 nm) and 11.1% for PIDTT-DTNT-OD. It was concluded that the side chains had a tiny impact on the aggregation ability in CB solution.

## Photostability

Apart from the ability to harvest sunlight for semiconducting copolymers, photostability is also an important issue because it is the basic requirement for commercialization of PSCs.<sup>25,70–73</sup> Thus, in order to inspect the effect of the side chains on the photostability, we examined the absorption changes of the studied copolymers by exposing the diluted CB solution and polymer films with thickness approximately 90 nm under AM 1.5 sunlight irradiation in air at ambient temperature. All films were prepared by spin-coating CB solution containing each polymer (ca 12 mg mL<sup>-1</sup>) onto pre-cleaned ITO/glass substrates. As shown in Fig. S12 in Appendix S1, the three copolymers exhibited a similar variation, i.e. the ICT absorption peak decreased and blue-shifted, and the  $\Box - \Box^*$  peak only decreased with an increase of the exposure time in CB solution. As seen from Fig. S12(d), after photo-degradation for 4h, PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD maintained 79.6%, 79.6% and 81.1% respectively of their initial light absorption. Furthermore, the UV-visible spectra changes of these copolymers in the film state are depicted in Fig. 3. For all copolymers, a reduced absorption intensity variation of the ICT and  $\Box - \Box^*$  peaks and 94.5%, 86.5% and 74.1% of their initial light absorption characteristics for PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD after 11 h of illumination in air were observed, which is in accordance with the results from XRD and DFT analyses, since the shortened and linear flexible side chain promoted dense and ordered packing, which perhaps suppressed the chance of triplet formation and impeded the diffusion of photo-oxidizing chemicals (such as oxygen and/or photoinduced radicals) into the stacked polymer chains.<sup>72,73</sup> Obviously, the side chain had little impact on photostability in solution but had a pronounced influence in films of the studied polymers.

## **XRD** properties

XRD analyses for the pristine polymers PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD and the corresponding polymer/PC<sub>61</sub>BM blend films were employed to probe the impact of the side chain on crystallinity and molecular packing in the solid state. Note that these thin films were prepared through casting from CB onto glass substrates. As indicated in Fig. 4(a), only PIDTT-DTNT-C16 bearing a long branched side chain exhibited two weak peaks, but PIDTT-DTNT-HD and PIDTT-DTNT-OD showed one peak. The observed broad diffraction peaks in the wide angle region reflecting the  $\Box - \Box$  stacking distance were located at of 23.70°, 22.92° and 22.24° for PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD, respectively, corresponding to D-D stacking distances of 3.75, 3.88 and 3.99Å according to Bragg'slaw(i.e.  $\Box = 2d\sin\Box$ ).<sup>74</sup>Thepeaks in the small angle region were located at 20 = 4.84° for PIDTT-DTNT-C16, corresponding to a distance of the polymer backbone separated by the flexible side chain which was 18.23 Å. For the blend films, no obvious diffraction peak was observed in the PIDTT-DTBT-C16:PC61BM film, PIDTT-DTNT-HD:PC61BM showed one strong diffraction peak at 20 = 20.14° and PIDTT-DTNT-OD:PC<sub>61</sub>BM exhibited one weak diffraction peak at  $2\square = 22.46^\circ$ , corresponding to  $\square - \square$ stacking distances of 4.40Å for PIDTT-DTNT-HD:PC61BM and 3.95 Å for PIDTT-DTNT-OD:PC<sub>61</sub>BM. Clearly, the [] – [] stacking interaction decreased gradually in the film of pure polymer; however, the blend film exhibited gradually enhanced D-D stacking interaction when the side chain changed from C16 to HD and to OD.

## **Electrochemical properties**

The electronic energy levels of the polymers are a crucial parameter of their PV application. The cyclic voltammetry (CV) method has been widely employed to measure the oxidation onset potentials ( $\Box_{ox}^{onset}$ ) of polymers and to estimate their  $E_{HOMO}$  and  $E_{LUMO}$ . To evaluate the impact of the side chain on energy levels, the corresponding CV curves for each copolymer film on a glass carbon electrode were recorded (Fig. 5(a)), and the detailed electrochemiphoration of the side chain on the detailed electrochemine the side chain on the detailed electrochemine the side chain of the side chain of the side chain on a glass carbon electrode were recorded (Fig. 5(a)), and the detailed electrochemine the side chain of the side chain of

and 0.70 V, respectively. Note that the CV curve is measured with regard to the potential of a standard Ag/AgNO<sub>3</sub> electrode calibrated with a ferrocene/ferrocenium (Fc/Fc<sup>+</sup>) redox couple. The  $\Box_{1/2}$  of the Fc/Fc<sup>+</sup> redox couple is determined to be 0.12 V *versus* the Ag/AgNO<sub>3</sub> reference electrode under identical conditions. Considering that the redox potential of Fc/Fc<sup>+</sup> is -4.8 eV relative to the vacuum energy level,  $E_{HOMO}$  can be calculated using  $E_{HOMO} = -e(\Box_{ox}^{onset} + 4.68)$  (eV).<sup>64,76</sup> Consequently, the corresponding  $E_{HOMO}$  valus were approximately -5.36, -5.36 and -5.38 eV for PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD, respectively. These relatively low-lying  $E_{HOMO}$  values which were close

to -5.40 eV for the ideal polymer were expected to acquire a higher V<sub>OC</sub> theoretically.<sup>29</sup> Since  $\Box$  electrons are prone to delocalize in a planar structure and to localize in a twisted structure, PIDTT-DTNT-OD exhibited a deepened  $E_{HOMO}$ ; this trend was consistent with the decreased planarity from DFT calculation (later).<sup>29</sup> Additionaly, based on  $E_q^{opt}$  and  $E_{HOMO}$ , the  $E_{LUMO}$  values were thus estimated to be -3.69, -3.71 and -3.72 eV for PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD, respectively, using the equation  $E_{LUMO} = E_{HOMO} + E_{g}^{opt}$ . For better comparison, the energy level diagram of the resultant donor copolymers and PC<sub>61</sub>BM is shown in Fig. 5(b). It is clear that the side chain produced an insignificant impact on the energy levels. All polymers exhibited a suitable ELUMO matched well with PC61BM and had LUMO gaps of about 0.48-0.51 eV, supporting enough driving force to realize exciton splitting and charge dissociation at the D-A interfaces, hence ensuring energetically beneficial electron transfer in order to conquer the binding energy for the intrachain exciton.75

## Theoretical calculations

To better understand the electron distribution and the backbone conformation of the side chain type in the studied polymers, calculations were performed by DFT calculation on the B3LYP/6-31G\* basis set, as executed in the Gaussian 09 program suite which was a quantum chemical program.<sup>77</sup> Considering the negligible impact on electron properties, the hexyl of IDTT was substituted with methyl, and the linear *n*-hexadecyl and branched 2-hexyldecyl/2-cotyl-dodecyl were replaced by n-butyl and iso-butyl, respectively, for simplicity. One repeating unit (unimer), denoted IDTT-DTNT-C16 and IDTT-DTNT-HD/OD, was selected as the corresponding model compound. As illustrated in Fig. 6, the HOMO orbitals are delocalized over the entire oligomer; in contrast, the LUMO orbitals are preferentially localized on the electron-deficient NT and bilateral thiophene bridges. It should be noted that the bridging sp<sup>3</sup>-carbon prevented the electron orbital interaction between the alkylphenyl side chain and the polymeric conjugated backbone, which did not contribute to the electron delocalization of the polymer; this was consistent with the observations from other groups.<sup>45,46</sup> Furthermore, the calculated  $E_{HOMO}$ ,  $E_{LUMO}$  and  $E_{a}$  are -4.71, -2.86 and 1.85 eV for PIDTT-DTNT-C16 and -4.75, -2.87 and 1.88 eV for PIDTT-DTNT-HD/PIDTT-DTNT-OD. As a whole, the trend in energy level is in accordance with the results from CV measurements. It has been demonstrated that the good planarity for the polymer backbone is instrumental in intrinsic D-D stacking, hence facilitating excellent charge carrier mobility.<sup>24</sup> Consequently, the dihedral angle D<sub>1</sub> between IDTT and the alkylthiophene bridge and the dihedral angles  $\Box_2$  and  $\Box_3$  between the alkylthiophene bridge and the NT moiety are shown in Fig. S13 in Appendix S1. These dihedral angles  $\Box_1$ , I and  $\Box$  were 18.56°, -5.04° and -1.88° for PIDTT-DTNT-C16 and  $\square_2$ 

-28.93, 6.47° and 0.11° for PIDTT-DTNT-HD/PIDTT-DTNT-OD, respectively, indicating that the planarity decreased when the side chain changed from linear C16 to branched HD/OD. It should be noted that all calculated data are higher in energy than those from experimental measurements, because only finite unimer and short side chains are taken into consideration in the DFT model to replace the CPs in our calculation process. Nevertheless, these calculation results by and large tally with the trends seen from experiment and still disclose the mutuality between molecular structure, optoelectronic properties and thus PV properties.



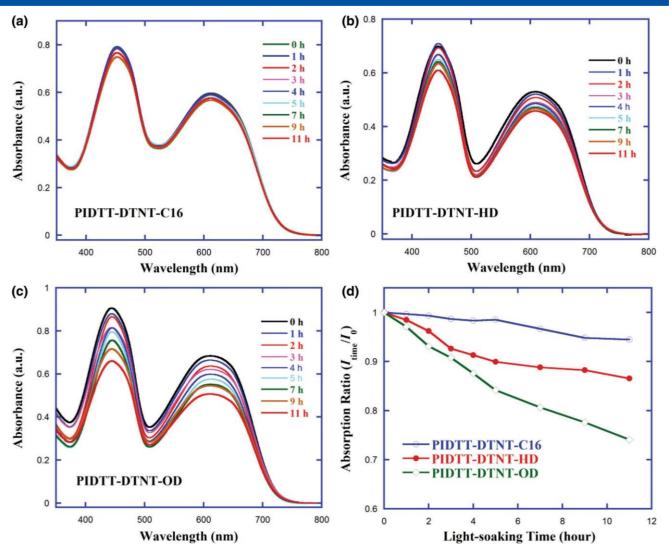


Figure 3. UV-visible absorption spectra changes after illumination of PIDTT-DTNT-C16 (a), PIDTT-DTNT-HD (b) and PIDTT-DTNT-OD (c) films on ITO, and a summary of light absorption intensity changes at the peak (ca620 nm) of each polymer as a function of light-soaking time (d).

Table 2. The optimized PV parameters of PSCs under AM 1.5G illumination						
Polymer	$V_{\rm OC}\left({\sf V}\right)$	J <sub>SC</sub> (mA cm <sup>-2</sup> )	FF (%)	PCE (%)	$R_{\rm SH}^{\rm b}(\Omega~{\rm cm}^2)$	$R_{\rm S}^{\rm b}(\Omega {\rm ~cm^2})$
PIDTT-DTNT-C16/PC <sub>61</sub> BM	0.83	4.67 (4.56) <sup>a</sup>	33.56	1.30	310	77
PIDTT-DTNT-HD/PC61BM	0.83	9.35 (9.27) <sup>a</sup>	42.80	3.31	257	26
PIDTT-DTNT-OD/PC <sub>61</sub> BM	0.80	3.70 (3.61) <sup>a</sup>	34.41	1.02	388	100

<sup>a</sup> The values in parentheses are the integrated currents obtained from the EQE curves.

<sup>b</sup>Shuntresistance ( $R_{SH}$ ) and series resistance ( $R_{S}$ ) are deduced from the inverse slope at V = 0 and  $V = V_{OC}$  in the J - V curves under illumination.

## Photovoltaic properties

To examine the influence of the side chain on PV performance, inverted BHJ PSCs with a structure of ITO/PFN/polymers:PC <sub>61</sub>BM/MoO<sub>3</sub>/Ag were fabricated.<sup>78</sup> A 10 nm thick alcohol-soluble PFN was chosen as a cathode interfacial modifier between the ITO and active layer, which can effectively further the interfacial contact and electron extraction between the active layer and metallic cathode.<sup>79</sup> An 8 nm thick MoO<sub>3</sub> was chosen as the anode interlayer modifier between the active layer and Ag electrode. The corresponding active layers were prepared by spin-coating from the CB solution involved in PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD and PC<sub>61</sub>BM. The J-V measurements were performed in simulated solar light at 100 mW cm<sup>-2</sup> under AM 1.5G illumination. The initial device optimization was carried out by screening the weight ratios of these studied polymers:PC<sub>61</sub>BM of 1:1, 1:1.5 and 1:2. The best PV performance was observed from the devices on the basis of a polymer to PC<sub>61</sub>BM weight ratio of 1:1.5, and the corresponding J-V curves are exhibited in Fig. S14 in Appendix S1; detailed PV data are listed in Table S3. It is seen that the device based on PIDTT-DTNT-C16 showed the best PCE of 1.01%, with a  $V_{OC}$  of 0.84 V, a  $J_{SC}$  of 3.79 mA cm<sup>-2</sup> and an FF of 31.54%, and the PIDTT-DTNT-HD-based device exhibited

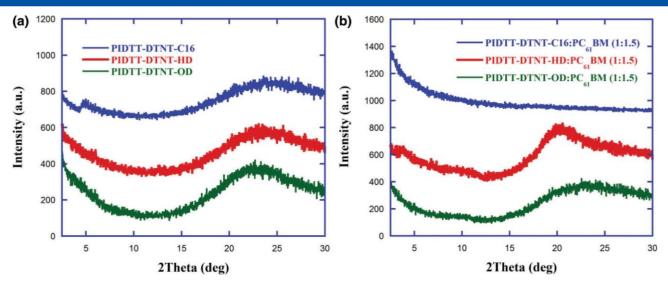


Figure 4. XRD patterns of the studied pure copolymers (a) and the blends (b) (polymer:PC<sub>61</sub>BM = 1:1.5).

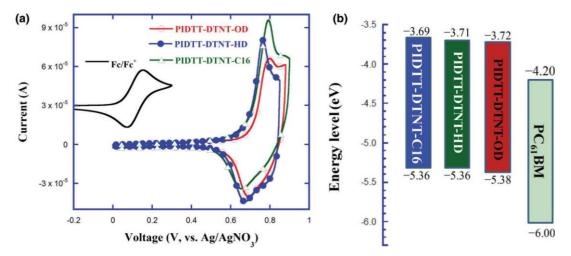


Figure 5. CV curves (a) and energy level schematic diagram (b) of copolymers PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD.

a relatively higher PCE of 1.86%, with a  $V_{OC}$  of 0.81V, a  $J_{SC}$  of 5.53 mA cm<sup>-2</sup> and an FF of 41.59%, but the PIDTT-DTNT-OD-based device exhibited the lowest PCE of 0.36%, with a  $V_{OC}$  of 0.78 V, a  $J_{SC}$  of 1.51 mA cm<sup>-2</sup> and an FF of 30.97%. It is clear that, with the side chain branching and lengthening, the PCE exhibited a decreased variation. The relatively low-lying  $E_{HOMO}$  made these devices containing PIDTT-DTNT-based polymers acquire a higher  $V_{OC}$  ranging from 0.78 to 0.84 V. These terrible PCEs were mainly restricted by the lower  $J_{SC}$  and FF. The  $J_{SC}$  variations were confirmed by the corresponding external quantum efficiency (EQE) spectra (Fig. S14); in particular, the EQE values in the range 500–750 nm were smaller than those ranging from 300 to 500 nm, which coincided with the former absorption spectra of the copolymers.

Many investigations have verified that the solvent additive 1,8-diiodoctane (DIO) having a higher boiling point than the processing solvent CB can improve the morphology of the active layers for BHJ PSCs to raise the PV performance.<sup>24,80</sup> Accordingly, we utilized 3% DIO (DIO/CB, v/v) as the solvent additive during the device-fabricating process in order to further maximize the PCE of the devices. The J-V curves are outlined in Fig. S14 in Appendix S1 and detailed data are also listed in Table S3. It was observed that the PIDTT-DTNT-C16-based device exhibited a small

enhanced PCE from 1.01% to 1.30% after utilizing DIO, mainly benefitting from slightly increased J<sub>SC</sub> (from 3.79 to 4.67 mAcm<sup>-2</sup>) and FF (31.54% to 33.56%). For PIDTT-DTNT-HD-based devices, it was found that the PCE was greatly enhanced from 1.86% to 3.31%, corresponding to largely elevated  $J_{SC}$  (from 5.53 to 9.35 mA cm<sup>-2</sup>) and slightly increased FF (41.59% to 42.80%) as well as slightly maximized V<sub>oc</sub> (from 0.81 to 0.83 V). As for the PIDTT-DTBT-OD-based device, the PCE was again found to be increased from 0.36% to 1.02%, which primarily originated from synchronously raised  $V_{\rm OC}$  (from 0.78 to 0.80 V),  $J_{\rm SC}$  (from 1.51 to 3.70 mA cm<sup>-2</sup>) and FF (30.97% to 34.41%). These dramatically increased  $J_{SC}$  were confirmed by EQE evaluations, as shown in Fig. S14. Obviously, PIDTT-DTNT-C16 containing a linear side chain exhibited the smallest enhancement and the copolymers involving branched chains produced the larger improvements. As is known, larger shunt resistances  $(R_{SH})$  and smaller series resistances  $(R_S)$  were beneficial to gaining higher FF. Thus  $R_{SH}$  and  $R_{S}$  values calculated from the J-Vcurves of devices at V = 0 and  $V = V_{OC}$ , respectively, are listed in Table S3. In detail, these decreased  $R_{\rm S}$  values (from 100 to 77  $\Omega$  cm<sup>2</sup> for PIDTT-DTNT-C16, from 43 to 26 Ω cm<sup>2</sup> for PIDTT-DTNT-HD and from 583 to  $100 \Omega$  cm<sup>2</sup> for PIDTT-DTNT-OD) can well account for the corresponding relatively small enhancements in FF (31.54% to

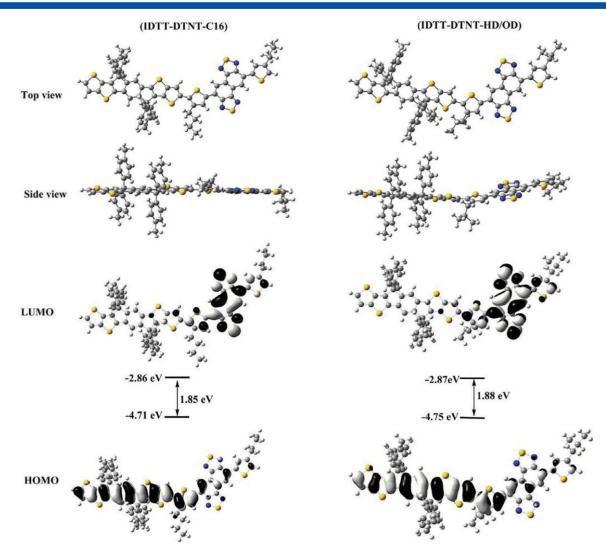


Figure 6. Optimized geometries and molecular orbital surfaces of the HOMO and LUMO for the unimer model compound, obtained with the B3LYP/6-31G\* basis set.

33.56% for PIDTT-DTNT-C16, 41.59% to 42.80% for PIDTT-DTNT-HD and 30.97% to 34.41% for PIDTT-DTNT-OD).

Assisted by D/A ratio screening and DIO additive utilization, the best J-V curves and EQE spectra of the studied copolymers are shown in Fig. 7 and the optimized PV data are listed in Table 2. We can see that the optimal PCE increased from 1.30% to 3.31% when the side chain changed from linear C16 to branched HD, chiefly benefitting from a 100% increase in  $J_{SC}$  (from 4.67 to 9.35 mA cm<sup>-2</sup>) and 27.53% enhancement in FF (from 33.56% to 42.80%) even with an unchanged V<sub>OC</sub>. Subsequently, after the side chain was further prolonged to OD, the PCE largely declined to about 69.2% (from 3.31% to 1.02%), which was primarily ascribed to simultaneous 3.6% (from 0.83 to 0.80 V), 60.4% (from 9.35 to 3.70 mA cm<sup>-2</sup>) and 19.6% (from 42.80% to 34.41%) deteriorations for the corresponding  $V_{OC}$ ,  $J_{SC}$  and FF of the devices. The variations of  $J_{SC}$  were validated by the corresponding EQE curve (Fig. 7(b)). The PIDTT-DTNT-C16-based device exhibited low EQE response (smaller than 20%) in the range 520 - 750 nm; meanwhile the PIDTT-DTNT-HD-based device showed an obviously improved EQE (between 40% and 60%) over the whole response range (300 - 750 nm). As for the PIDTT-DTNT-OD-based device, the EQE profile was similar

to that of PIDTT-DTNT-HD but the response was inferior. Also, integrated  $J_{SC}$  values from the EQE curves were 4.56, 9.27 and 3.61 mA cm<sup>-2</sup> for the best-performing PIDTT-DTNT-C16:PC<sub>61</sub>BM, PIDTT-DTNT-HD:PC<sub>61</sub>BM and PIDTT-DTNT-OD:PC<sub>61</sub>BM, respectively, indicative of an error of less than 5% compared to the  $J_{SC}$  values from J-V tests. Moreover, the variations in FF were confirmed by the trend of first decreasing and then increasing  $R_S$  (from 77 to 26 then to 100  $\Omega$  cm<sup>2</sup>) after the flexible side chain was changed from C16 to HD and then to OD. All in all, the PIDTT-DTNT-HD exhibited at least a 1.53-fold enhancement in PCE compared to the polymers bearing C16 and OD side chains.

#### Hole mobility

It has been demonstrated that charge mobility undoubtedly plays an important role in affecting the PV performance because it is directly related to charge transport and recombination.<sup>14,81,82</sup> In order to further assess the vertical hole transport character of these copolymers, hole-only and electron-only devices of polymer:PC<sub>61</sub>BM blend films were fabricated with the device configurations of ITO/poly(3,4ethylenedioxythiophene):poly(styrenesulfonate) (PEDOT:PSS)/

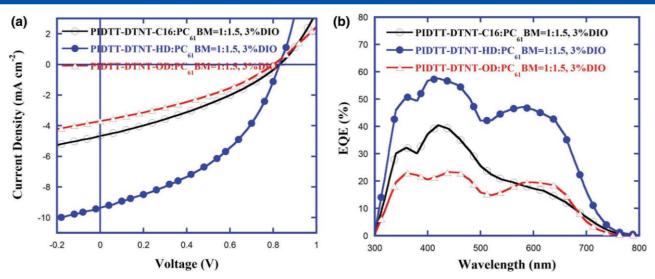


Figure 7. The optimized *J* – *V* curves (a) and the EQE spectra (b) for the PSCs based on the studied copolymers containing different side chains.

blend/MoO<sub>3</sub>/Ag and ITO/ZnO/blend/MoO<sub>3</sub>/Al under identical conditions of the corresponding optimized PSCs. Note that the thicknesses of PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD were 114, 133 and 137 nm for hole-only devices and 95, 125 and 120 nm for electron-only devices, respectively. The J-V and  $J^{1/2}-V$  characteristics for the blend films were obtained in the dark for hole-only and electron-only devices, as shown in Fig. S15 and Fig. 8, respectively. It is shown that the hole mobility  $(\square_h)$  and electron mobility  $(\square_a)$  are  $1.47 \times 10^{-4}$ and  $4.60 \times 10^{-7}$  for PIDTT-DTNT-C16,  $1.10 \times 10^{-5}$  and  $6.48 \times 10^{-7}$ for PIDTT-DTNT-HD and  $1.37\times10^{-5}$  and  $6.60\times10^{-5} cm^2 V^{-1} s^{-1}$ for PIDTT-DTNT-OD (Tables S4 and S5), respectively. Clearly, the hole mobility showed a decreasing tendency; however, the electron mobility exhibited first an enhanced and then a decreased trend when the side chain was changed from linear C16 to the branched HD and OD. Furthermore, from Table 3, the values of the  $\Box_h/\Box_e$  ratio are 319.5 for PIDTT-DTNT-C16, 16.9 for PIDTT-DTNT-HD and 207.7 for PIDTT-DTNT-OD. The more balanced Dh/De observed in the PIDTT-DTNT-OD-based device can partially account for the higher FF and thus improved J<sub>SC</sub>.<sup>14,81–83</sup>

Table 3. Mobility data of the studied polymers containing different side chains						
Active layer	$\Box_h{}^a(cm^2 V^{-1} s^{-1})$	□ <sub>e</sub> <sup>b</sup> (cm <sup>2</sup> V <sup>-1</sup> s <sup>-1</sup> )	□ <sub>h</sub> /□ <sub>e</sub>			
PIDTT-DTNT-C16: PC <sub>61</sub> BM = 1:1.5	1.47 × 10 <sup>-4</sup>	4.60 × 10 <sup>-7</sup>	319.5			
PIDTT-DTNT-HD:PC <sub>61</sub> BM = 1:1.5	1.10 × 10 <sup>−5</sup>	6.48 × 10 <sup>-7</sup>	16.9			
PIDTT-DTNT-OD:PC <sub>61</sub> BM = 1:1.5	1.37 × 10 <sup>-5</sup>	6.60 × 10 <sup>-8</sup>	207.7			
$^{\rm a}$ Hole-only devices with the structure of ITO/PEDOT:PSS/polymer: PC_{61}BM/MoO_3/Ag. $^{\rm b}$ Electron-only devices with the structure of ITO/ZnO/polymer: PC_{61}BM/PFN/AI.						

## Morphological properties

The morphology of the active layer for BHJ PSCs is an important factor to determine the charge generation and the extraction properties of PSCs.<sup>74,80,84</sup> In order to explain why PIDTT-DTNT-HD

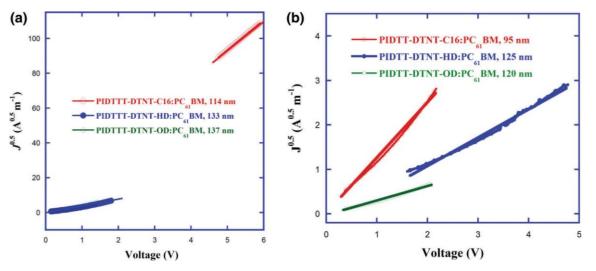
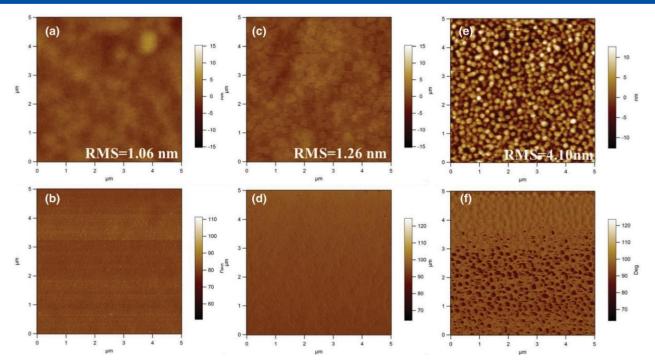


Figure 8.  $J^{1/2} - V$  characteristics of hole-only (a) and electron-only (b) devices of the studied copolymers containing different side chains.



**Figure 9.** Tapping AFM height (upper) and phase (bottom) images of the active layers of (a), (b) PIDTT-DTNT-C16:PC<sub>61</sub>BM (1:1.5, 3% DIO), (c), (d) PIDTT-DTNT-HD:PC<sub>61</sub>BM (1:1.5, 3% DIO) and (e), (f) PIDTT-DTNT-OD: PC<sub>61</sub>BM (1:1.5, 3% DIO). Image size  $5 \times 5 \mu m$ . RMS, root mean square roughness.



Figure 10. TEM bright field images of the active layers for (a) PIDTT-DTNT-C16/PC<sub>61</sub>BM (1:1.5, 3% DIO), (b) PIDTT-DTNT-HD/PC<sub>61</sub>BM (1:1.5, 3% DIO) and (c) PIDTT-DTNT-OD/PC<sub>61</sub>BM (1:1.5, 3% DIO).

containing the branched HD side chain yielded a relatively enlarged PCE, we applied the tapping-model AFM measurement to examine the surface morphologies, as shown in Fig. 9. Note that all blend films were prepared under exactly the same conditions as those of the optimal device. It is shown that the root-mean-square roughness of the blend films was 3.06 nm for PIDTT-DTNT-C16:PC61BM, 1.26 nm for PIDTT-DTNT-HD:PC61BM and 4.10 nm for PIDTT-DTNT-OD:PC61BM. The gradually increased surface roughness was identical with the aggregation trend observed in the former blend film when the side chain was changed from C16 to HD to OD. It is noted that PIDTT-DTNT-OD exhibited a pinhole-like morphology, which is bad for improving the PCE. Besides, TEM was further utilized to examine the in-depth morphology of the active layers. From Fig. 10, PIDTT-DTNT-C16 exhibited poor phase separation, which cannot sufficiently supporttheD-Ainterfacial areas to promote exciton dissociation into free charges. When C16 was changed into HD and OD, the phase separation was slightly improved. The observed morphological information can partly explain the reason for the relatively higher FF and J<sub>SC</sub> in the PIDTT-DTNT-HD-based device.<sup>64,85–88</sup>

# CONCLUSION

To sum up, three D-D-A type CPs PIDTT-DTNT-C16, PIDTT-DTNT-HD and PIDTT-DTNT-OD bearing diverse flexible side chains were designed and synthesized to investigate the influence of the side chain on absorption, electrochemical properties, backbone conformation and PV properties. As a result of incorporating a medium IDTT donor unit and a strong NT acceptor into the polymer backbone, the copolymers exhibited a medium optical bandgap of ca 1.66 eV ranging from 300 to 750 nm and a low-lying  $E_{\rm HOMO}$  of about -5.36 V. The side chain gave rise to an insignificant impact on the absorption, aggregation and photostability in CB solution, as well as energy levels, but a non-negligible influence on absorption, photostability and aggregation behavior in the film state. It is shown that PIDTT-DTNT-C16 possessing the densest and most ordered packing structure exhibited the best photostability. Meanwhile, PIDTT-DTNT-HD with branched HD side chain showed a 1.53 times enhancement in PCE of 3.31%, which chiefly benefitted from its slightly improved absorption, more balanced  $\Box_{\rm h}/\Box_{\rm e}$  and morphology of the active layer as a result of introducing the branched HD side chain into the IDTT-DTNT backbone.

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# SUPPORTING INFORMATION

Supporting information may be found in the online version of this article.

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